: 511278968

====== WPI ======

TI - Coating for yttrium silicate film formed on silicon carbide - involves coating oxides of boron, zinc, sodium and iron and heat treating

AB - JP11278968 NOVELTY - Any one or two of B203, ZnO, Na2CO3 and Fe2O3 are mixed and coated over surface of Y2SiO5 and heat treated.

- USE - For yttrium silicate film formed on silicon carbide.

- ADVANTAGE - Improves oxidation resistance of silicon carbide.

- (Dwg.0/5)

- JP11278968 A 19991012 DW199954 C04B41/89 005pp

PR - JP19980085544 19980331

PA - (MITO ) MITSUBISHI JUKOGYO KK

MC - L02-G12 L02-J02C

DC - L02

PN

IC - B01J19/00 ;C04B41/87 ;C04B41/89

AN - 1999-629172 [54]

## PAJ =====

TI - METHOD FOR IMPROVING AIR-TIGHTNESS OF DIYITRIUM SILICON PENTOXIDE COATING FILM

AB - PROBLEM TO BE SOLVED: To increase the air-tightness of a Y2 SiO5 coating film and completely prevent the oxygen attack on the surface of a part from outer environment by coating a surface of a Y2 SiO5 coating film with an oxide composed of B2 O3 , ZnO, Na2 CO3 or Fe2 O3 or their arbitrary mixture and heat-treating the coated product.

- SOLUTION: The surface of a Y2 SiO5 coating film formed on the surface of a part is coated with B2 O3 , ZnO, Na2 CO3 or Fe2 O3 or their arbitrary mixture and heat-treated at 1573-1973 K for 1-100 hr to increase the air-tightness of the Y2 SiO5 coating film. The oxide to be applied to the surface of Y2 SiO5 may be incorporated with <=70 mol.% of Y2 O3 , SiO2 or their mixture. The applied oxide is introduced into the open pare of the Y2 SiO5 coating film to close the open pore and remarkably improve the air-tightness of the Y2 SiO5 coating film. Accordingly, the oxygen attack on the surface of the part from outer environment is sufficiently prevented to get a satisfiable oxidation inhibiting effect.

PN - JP11278968 A 19991012

PD - 1999-10-12

ABD - 20000131

ABV - 200001

AP - JP19980085544 19980331

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I - C04B41/89 ;B01J19/00 ;C04B41/87